1

Schottky Rectifier, 10 A

Base cathode

ό1

Anode

Q 4, 2

20 mJ

dз

Anode

FEATURES

- Low forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability
- Popular D-PAK outline
- Small foot print, surface mountable
- High frequency operation
- AEC-Q101 qualified
- Meets JESD 201 class 2 whisker test
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-10WQ045FNHM3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

Document Number: 94737

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | | | |
|-----------------------------------|--|------------------------|----|--|--|--|--|--|
| SYMBOL | CHARACTERISTICS | CHARACTERISTICS VALUES | | | | | | |
| I _{F(AV)} | Rectangular waveform | 10 | А | | | | | |
| V _{RRM} | | 45 | V | | | | | |
| I _{FSM} | t _p = 5 μs sine | 400 | A | | | | | |
| V _F | 10 A _{pk} , T _J = 125 °C | 0.53 | V | | | | | |
| TJ | Range | - 40 to 175 | °C | | | | | |

| VOLTAGE RATINGS | | | | | | |
|--------------------------------------|------------------|-----------------|-------|--|--|--|
| PARAMETER | SYMBOL | VS-10WQ045FNHM3 | UNITS | | | |
| Maximum DC reverse voltage | V _R | 45 | V | | | |
| Maximum working peak reverse voltage | V _{RWM} | 40 | V | | | |

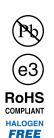
| ABSOLUTE MAXIMUM RATINGS | | | | | | | |
|--|------------------|---|---|--------|-------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | | VALUES | UNITS | | |
| Maximum average forward current See fig. 5 | | 50 % duty cycle at T_{C} = 157 °C, rectangular waveform | | 10 | A | | |
| Maximum peak one cycle non-repetitive surge current | I _{FSM} | 5 µs sine or 3 µs rect. pulse | Following any rated load condition and with | 400 | A | | |
| See fig. 7 | | 10 ms sine or 6 ms rect. pulse | rated V _{RRM} applied | 75 | | | |
| Non-repetitive avalanche energy | E _{AS} | $T_J = 25 \text{ °C}, I_{AS} = 3 \text{ A}, L = 4.4 \text{ mH}$ | | 20 | mJ | | |
| Repetitive avalanche current | I _{AR} | Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical | | 3.0 | А | | |

D-PAK (TO-252AA)

E_{AS}

Revision: 21-Aug-13

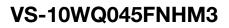
| PRODUCT SUMMARY | | | | | | | |
|---------------------|------------------|--|--|--|--|--|--|
| Package | D-PAK (TO-252AA) | | | | | | |
| I _{F(AV)} | 10 A | | | | | | |
| V _R | 45 V | | | | | | |
| V_F at I_F | 0.53 V | | | | | | |
| I _{RM} | 15 mA at 125 °C | | | | | | |
| T _J max. | 175 °C | | | | | | |
| Diode variation | Single die | | | | | | |





VS-10WQ045FNHM3

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| ELECTRICAL SPECIFICATIONS | | | | | | | |
|--|---------------------------------|--|-------------------------------|-------|------|--|--|
| PARAMETER | ARAMETER SYMBOL TEST CONDITIONS | | VALUES | UNITS | | | |
| | | 10 A | T _{.1} = 25 °C | 0.63 | V | | |
| Maximum forward voltage drop | V _{FM} ⁽¹⁾ | 20 A | 1j = 25 0 | 0.80 | | | |
| See fig. 1 | VFM (*) | 10 A | T, = 125 °C | 0.53 | | | |
| | | 20 A | 1j = 125 0 | 0.71 | | | |
| Maximum reverse leakage current | imum reverse leakage current | | $V_{\rm B} = Rated V_{\rm B}$ | 1 | mA | | |
| See fig. 2 | IRM \'' | T _J = 125 °C | VR - Haleu VR | 15 | IIIA | | |
| Threshold voltage V _{F(TO} | | $T_J = T_J$ maximum | | 0.255 | V | | |
| orward slope resistance r _t | | | | 22 | mΩ | | |
| Typical junction capacitance | CT | V_{R} = 5 V_{DC} (test signal range 100 kHz to 1 MHz), 25 $^{\circ}\mathrm{C}$ | | 760 | pF | | |
| Typical series inductance | L _S | Measured lead to lead 5 m | m from package body | 5.0 | nH | | |

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

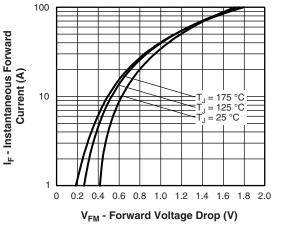
| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | |
|---|--|----------------------------|-------------|-------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | |
| Maximum junction and storage temperature range | T _J ⁽¹⁾ , T _{Stg} | | - 40 to 175 | °C | | |
| Maximum thermal resistance, junction to case | R _{thJC} | DC operation See fig. 4 | 2.0 | °C/W | | |
| Maximum thermal resistance, junction to ambient | R _{thJA} | | 50 | C/W | | |
| Approximate weight | | | 0.3 | g | | |
| | | | 0.01 | oz. | | |
| Marking device | | Case style D-PAK | 10WQ0 | 45FNH | | |

Note

 $^{(1)} \quad \frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$

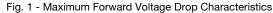
VS-10WQ045FNHM3

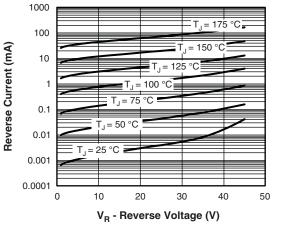
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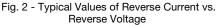


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SHA'







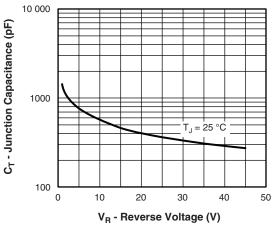


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

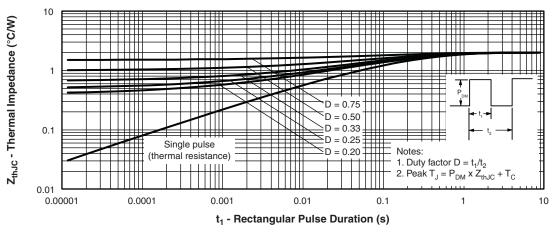


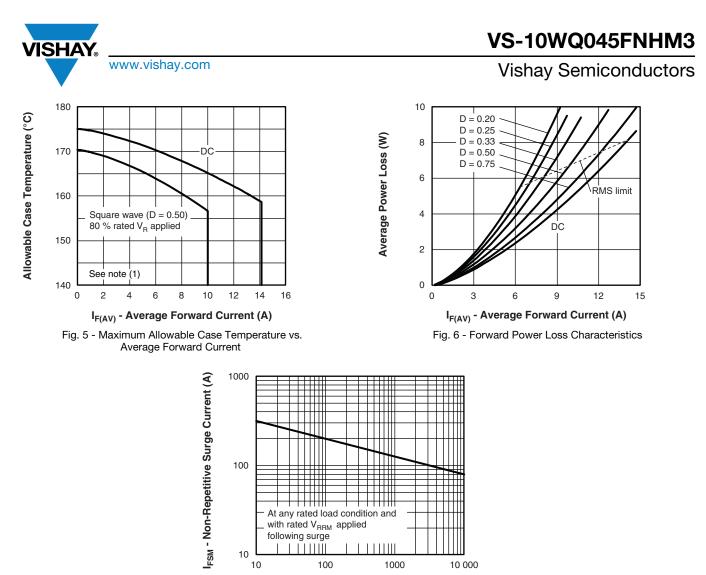
Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

Revision: 21-Aug-13

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t_p - Square Wave Pulse Duration (µs)

Fig. 7 - Maximum Non-Repetitive Surge Current

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \, x \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \, x \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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ORDERING INFORMATION TABLE

www.vishay.com

VISHAY

| Device code | VS- | 10 | W | Q | 045 | FN | TRL | Н | М3 |
|-------------|-----|--------|-----------|------------------------|------------|----------|----------|---------|----------|
| | 1 | 2 | 3 | 4 | 5 | 6 | (7) | 8 | 9 |
| | 1 - | - Visl | nay Sen | nicondu | ctors pro | oduct | | | |
| | 2 - | Cur | rent rati | ng (10 A | A) | | | | |
| | 3 - | - Pac | kage id | entifier: | | | | | |
| | _ | W = | D-PAK | | | | | | |
| | 4 - | Sch | ottky "G |)" series | | | | | |
| | 5 - | Vol | age rati | ng (045 | = 45 V) | | | | |
| | 6 | - FN | = TO-2 | 52AA (D | -PAK) | | | | |
| | 7 - | • N | one = T | ube | | | | | |
| | | • TI | R = Tap | e and re | el | | | | |
| | | • TF | RL = Ta | pe and ı | eel (left | oriente | d) | | |
| | | • TF | RR = Ta | pe and | reel (rigl | ht orien | ted) | | |
| | 8 | • Н= | AEC-Q | 101 qua | alified | | | | |
| | 9 - | | | ntal digit en-free, | | complia | int, and | termina | tions le |

| ORDERING INFORMATION (Example) | | | | | | | |
|--------------------------------|------------------|------------------------|-------------------------|--|--|--|--|
| PREFERRED P/N | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | | | |
| VS-10WQ045FNHM3 | 75 | 3000 | Antistatic plastic tube | | | | |
| VS-10WQ045FNTRHM3 | 2000 | 2000 | 13" diameter reel | | | | |
| VS-10WQ045FNTRRHM3 | 3000 | 3000 | 13" diameter reel | | | | |
| VS-10WQ045FNTRLHM3 | 3000 | 3000 | 13" diameter reel | | | | |

| LINKS TO RELATED DOCUMENTS | | | | | |
|----------------------------|--------------------------|--|--|--|--|
| Dimensions | www.vishay.com/doc?95519 | | | | |
| Part marking information | www.vishay.com/doc?95518 | | | | |
| Packaging information | www.vishay.com/doc?95033 | | | | |

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